



SDM1100S1F

SURFACE MOUNT SCHOTTKY BARRIER DIODE

Product Summary

V _{RRM} (V)	I _O (A)	V _{F(MAX)} (V) @+25°C	I _{R(MAX)} (μA) @+25°C
100	1.0	0.82	5

Description and Applications

The device is a single rectifier packaged in SOD123F (Type B). Offering low V_F and excellent high temperature stability this device is ideal for use in general rectification applications as a:

- Boost Diode
- Blocking Diode

Features and Benefits

- Low forward voltage (V_F) minimizes conduction losses and improving efficiency
- Reduced High Temperature Reverse Leakage; Increased Reliability against Thermal Runaway Failure in High Temperature Operation
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOD123F (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Polarity: Cathode Band
- Weight: 0.015 grams (Approximate)

SOD123F (Type B)





Top View

Bottom View

Ordering Information (Note 4)

Part Number	Case	Packaging
SDM1100S1F-7	SOD123F (Type B)	3000/Tape & Reel

Notes:

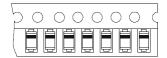
- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



DA = Product Type Marking Code YM = Date Code Marking Y = Year (ex.: C = 2015)

M = Month (ex.: 9 = September)



Date Code Key

Year	2013	2014	2015	2016	2017	2018	2019	2020
Code	Α	В	С	D	E	F	G	Н

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	100	>
Average Rectified Output Current	lo	1	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	50	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	135	°C/W
Typical Thermal Resistance, Junction to Case (Note 5)	$R_{ heta JC}$	20	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	85	°C/W
Typical Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	12	°C/W
Operating Junction Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	$V_{(BR)R}$	100	_	_	V	$I_R = 1.0 \text{mA}$
Forward Voltage Drop	V _F	_ _ _	0.75 0.81 0.60	0.82 — —	V	$I_F = 1A$, $T_J = +25$ °C $I_F = 2A$, $T_J = +25$ °C $I_F = 1A$, $T_J = +125$ °C
Leakage Current (Note 7)	I _R		0.15 0.110	5 5	μA mA	$V_R = 100V, T_J = +25^{\circ}C$ $V_R = 100V, T_J = +125^{\circ}C$
Total Capacitance	Ст	_	28	_	pF	$V_R = 4V$, $f = 1MHz$

Notes:

- 5. Device mounted on 1 x MRP FR-4 PC board, 2oz.
- S. Device mounted on 1 inch sq. copper pad, 2oz.
 Short duration pulse test used to minimize self-heating effect.

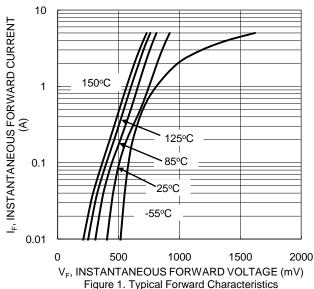
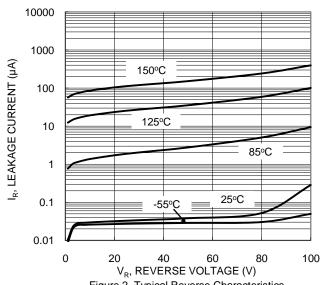
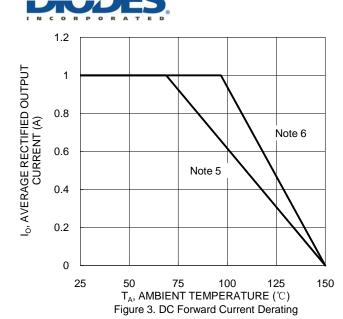
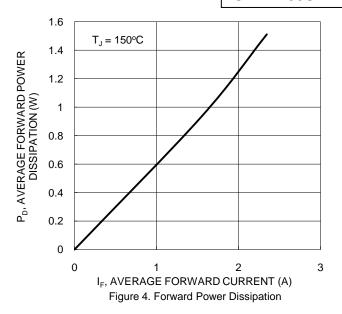
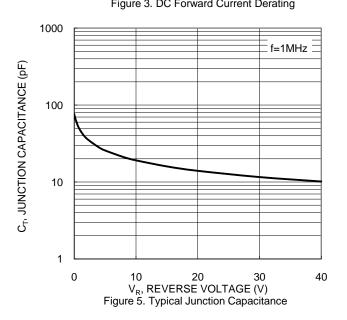


Figure 1. Typical Forward Characteristics





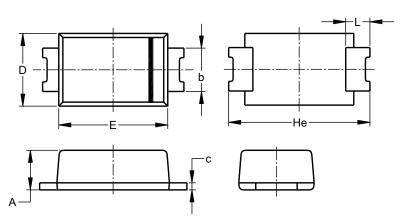




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F (Type B)



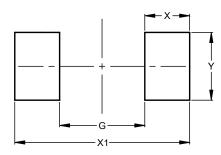
SOD123F (Type B)								
Dim	Min	Max	Тур					
Α	0.81	1.15						
b	0.80	1.35						
С	0.05	0.30						
D	1.70	1.90	1.80					
Е	2.60	2.80	2.70					
He	3.30	3.70	3.50					
L	0.35	0.85						
All	All Dimensions in mm							



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F (Type B)



Dimensions	Value (in mm)
G	1.90
Х	1.00
X1	3.90
Υ	1.50

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2016, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: SDM1100S1F-7